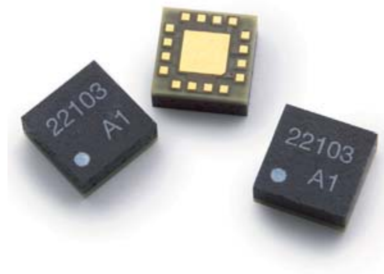
MGA-22103

2.5-2.7 GHz WiMAX Power Amplifier Module

Data Sheet

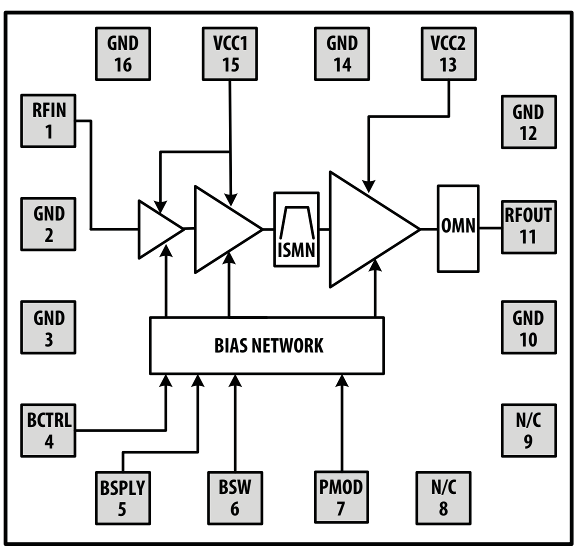


Description

Avago Technologies MGA-22103 power amplifier module is designed for mobile and fixed wireless data applications in the 2.5 to 2.7 GHz frequency range. The aggressive gain shape limits the noise injected into radio receivers co-located in the same device. The PA is optimized for IEEE 802.16 WiMAX modulation but can be used for any high linearity applications. The PA exhibits flat gain and good match while providing linear power efficiency to meet stringent mask conditions. It utilizes Avago Technologies proprietary GaAs Enhancement-mode pHEMT technology for superior performance across voltage and temperature levels.

The MGA-22103 is packaged in a 3 x 3 x 1 mm package for space-constrained applications.

Functional Block Diagram



Features

- Advanced GaAs E-pHEMT
- 50 Ω all RF ports
- 25dB gain step in low power mode with reduced Idsq
- Integrated CMOS compatible pins for shutdown and low power mode
- 3 to 5 V supply
- Adjustable bias current with BCTRL pin
- Small size: 3 x 3 x 1 mm
- Stable under all loads or conditions
- -40° C to +85° C operation

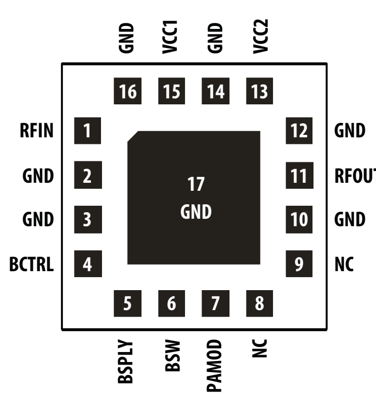
At 2.5 GHz (BCTRL = 2.8 V)

- Gain of 34 dB
- PAE of 21% at SEM compliant Pout = 25 dBm
- Meets 802.16 masks at 25 dBm Pout , 16 QAM WiMAX with 3.3 V and 437 mA
- 16 QAM WiMAX EVM < -32 dB (2.5%) at 25 dBm
- Low power Idd, 85 mA at Pout = 0 dBm

Applications

- Portable WiMAX applications with stringent coexistence requirements

Package Diagram



Electrical Specifications

Absolute Minimum and Maximum Ratings

Table 1. Minimum and Maximum Ratings

Parameter			Specifications			
Description		Pin	Min.	Max.	Unit	Comments
Supply Voltage		VCC1 VCC2		5.5	V	
Bias Supply		BSPLY	3	5.5	V	
Bias Control		BCTRL	1.65	5.5	V	
Bias ON/OFF		BSW	1.65	5.5	V	
Mode Control		PAMOD	1.65	5.5	V	
RF Input Power		RFIN		15	dBm	Using 16 QAM ¾
MSL				MSL3		
Channel Temperature				150	°C	
Storage Temperature			-65	150	°C	
ESD	Human Body Model			1000	V	
	Man Machine Model			50	V	

Table 2. Recommended Operating Range

Parameter		Specifications				
Description	Pin	Min.	Typical	Max.	Unit	Comments
Supply Voltage	VCC1 VCC2	3	3.3	5	V	
Bias Supply	BSPLY	3	3.3	5	V	
			13		mA	
Bias Control	BCTRL	2.75	2.8	2.85	V	
			0.7		μA	
Bias ON/OFF	BSW	1.65	1.8	3.3	V	
			7		uA	
Mode Control	PAMOD	1.65	1.8	3.3	V	
			17		μA	
RF Output Power	RFOUT		25	27	dBm	Using 16 QAM ¾
Frequency Range		2.5		2.7	GHz	
Thermal Resistance, θ_{ch-b}			23.4		°C/W	Channel to board
Case Temperature		-40		+85	°C	

WiMAX (802.16e) Electrical Specifications

All data measured on an FR4 demo board at Vcc1 = Vcc2 = 3.3 V, BCTRL = 2.8 V, Tc = 25° C, 50 Ω at all ports. Unless otherwise specified, all data is taken with OFDM 16-QAM ¾ convolutional coding modulated signal per IEEE 802.16e with 10 MHz BW operating over the BW of 2.5 GHz to 2.7 GHz.

Table 3. RF Electrical Characteristics

Parameter		Performance Min.	Typical	Max.	Unit	Comments
Input Return Loss			-10		dB	
Gain Flatness			1		dB	Over any 10 MHz
Gain Variation (V_{CC})		-1		1	dB	3 V to 5 V
High Power Mode	EVM		-34	-30	dB	Vcc = 3.3 V
			-36	-32		Vcc = 3.6 V
	SEM-A @ 5.05 MHz		-20	-13	dBm/100 kHz	IBW = 100 kHz
	SEM-B @ 6.5 MHz		-20	-13	dBm/MHz	IBW = 1 MHz
	SEM-C @ 10.5 MHz		-26	-19		
	SEM-D @11.5 MHz		-27	-25		
	SEM-E @15.5 MHz		-37	-29.5		
	SEM-F @ 20.5 MHz		-40	-37		
	Pout (SEM Compliant)	+25			dBm	802.16e
	Total DC Current		437		mA	Pout = 25 dBm
	Gain	31	34	37	dB	
Low Power Mode	EVM		-36		dB	Pout = 0 dBm
	Gain Step	18	23	24	dB	
	Total DC Current		85		mA	Pout = 0 dBm
P1dB			31		dBm	CW Single Tone
Psat			32		dBm	CW Single Tone
2fo			-36		dBm/MHz	
Settling Time		0.2	0.5		µS	
Icc leakage current			10	40	µA	Max current specified at 85° C
Noise Power in Cell Band			-146		dBm/Hz	
Noise Power in GPS Band			-149		dBm/Hz	
Noise Power in PCS			-144		dBm/Hz	

Selected performance plots

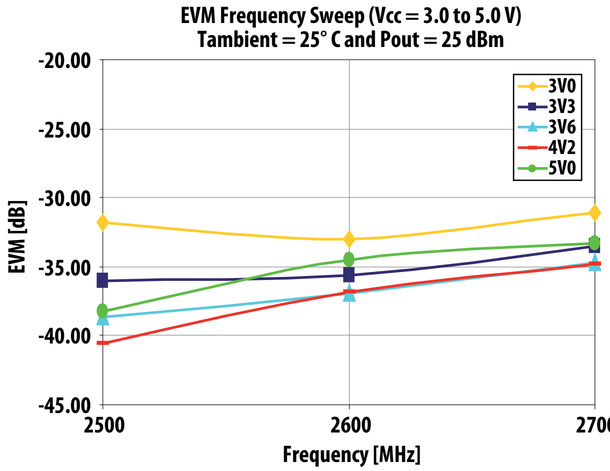


Figure 1. EVM Frequency Sweep at 25° C and Pout = 25 dBm over Vcc

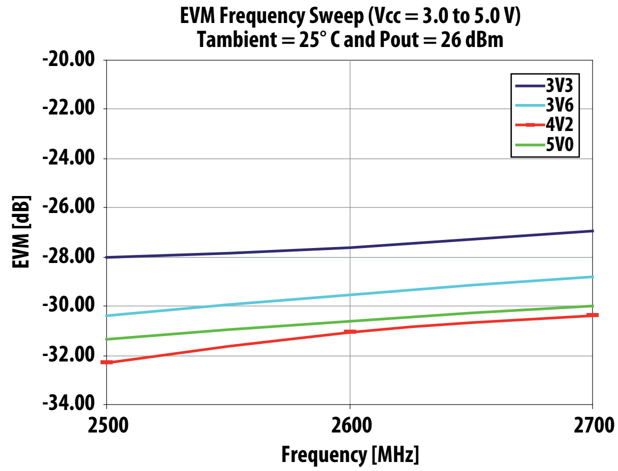


Figure 2. EVM Frequency Sweep at 25° C and Pout = 26 dBm over Vcc

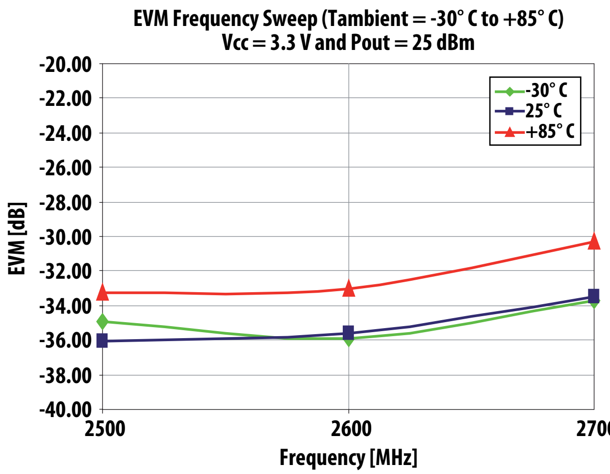


Figure 3. EVM Frequency Sweep at Vcc = 3.3 V and Pout = 25 dBm over Tambient

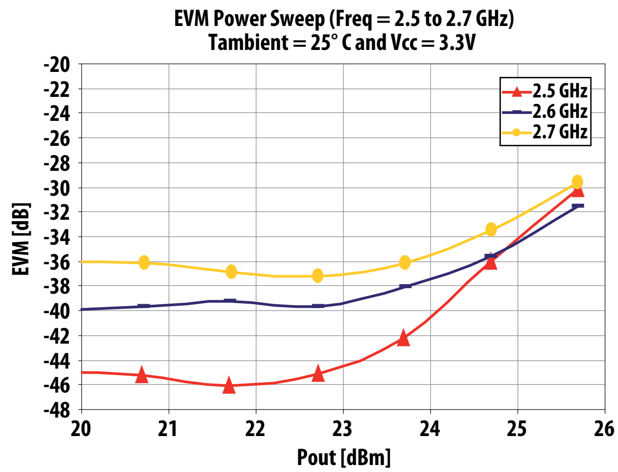


Figure 4. EVM Power Sweep at Vcc = 3.3 V and 25° C over Frequency

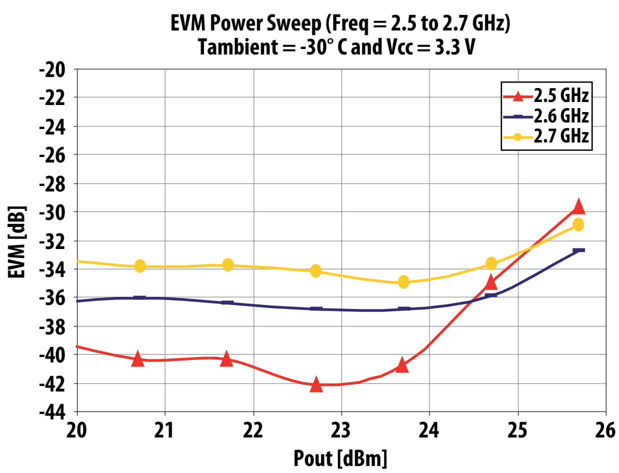


Figure 5. EVM Power Sweep at Vcc = 3.3 V and -30° C over Frequency

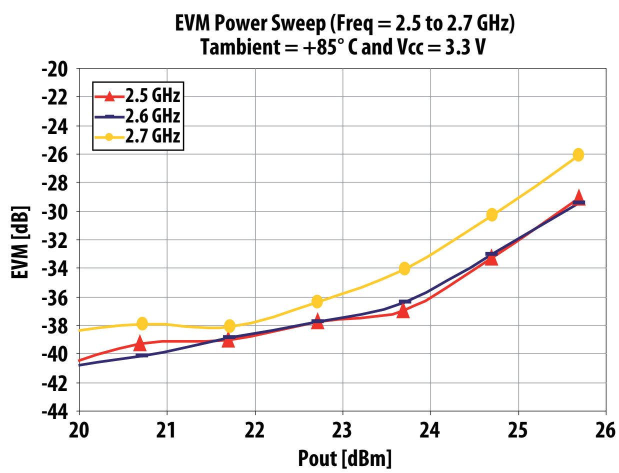


Figure 6. EVM Power Sweep at Vcc = 3.3 V and +85° C over Frequency

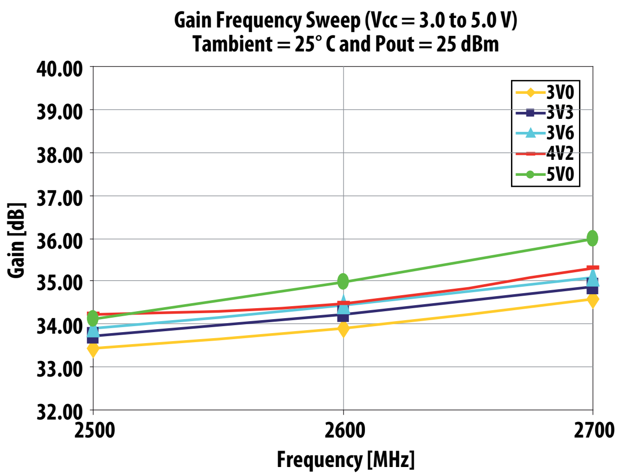


Figure 7. Gain Frequency Sweep at 25° C and Pout = 25 dBm over Vcc

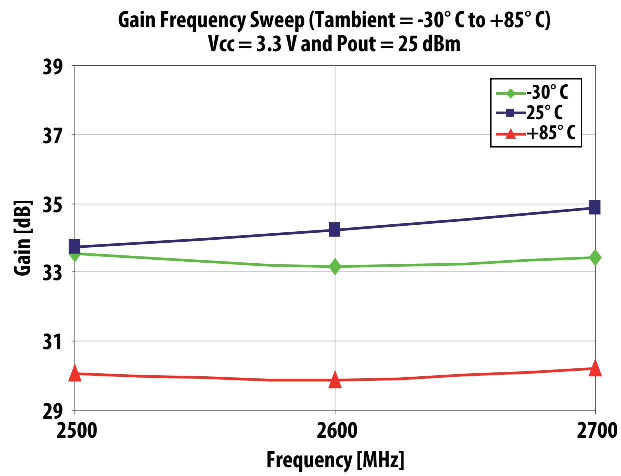


Figure 8. Gain Frequency Sweep at Vcc = 3.3 V and Pout = 25 dBm over Tambient

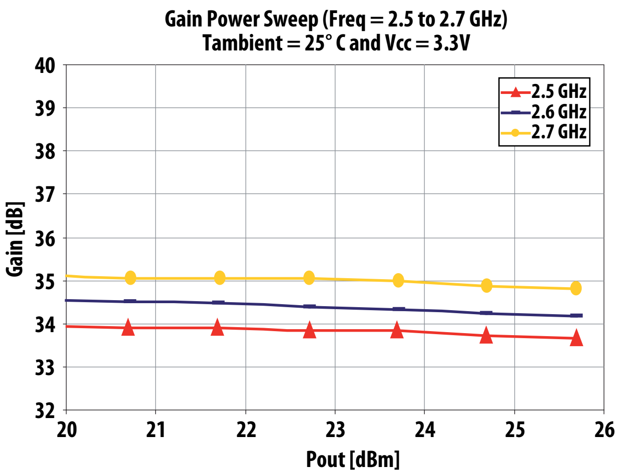


Figure 9. Gain Power Sweep at Vcc = 3.3 V and 25° C over Pout

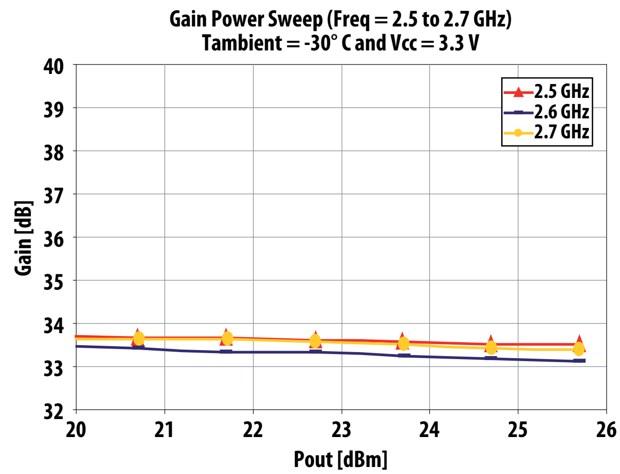


Figure 10. Gain Power Sweep at Vcc = 3.3 V and -30° C over Pout

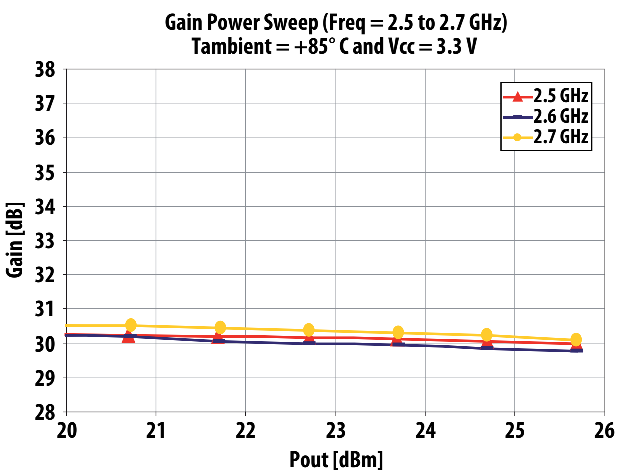


Figure 11. Gain Power Sweep at Vcc = 3.3 V and +85° C over Pout

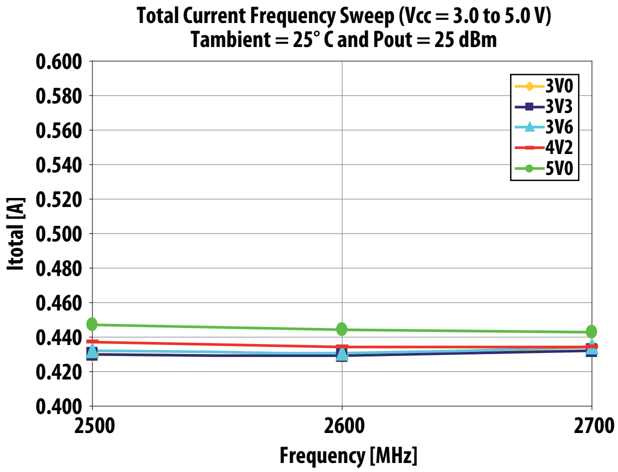


Figure 12. Total Current Frequency Sweep at 25° C and Pout = 25 dBm over Vcc

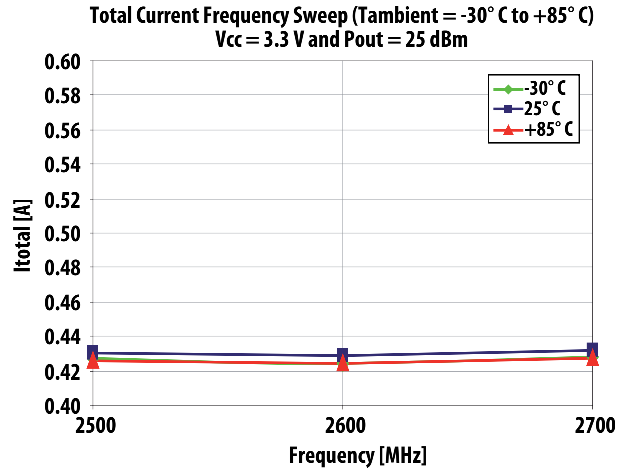


Figure 13. Total Current Frequency Sweep at 3.3 V and Pout = 25 dBm over Tambient

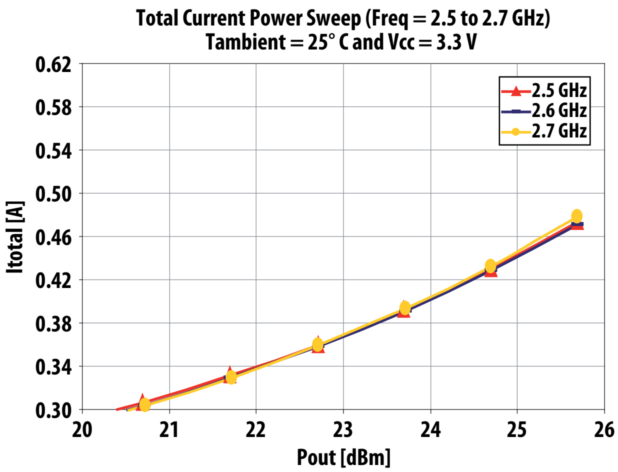


Figure 14. Total Current Power Sweep at 3.3 V and 25° C over Frequency

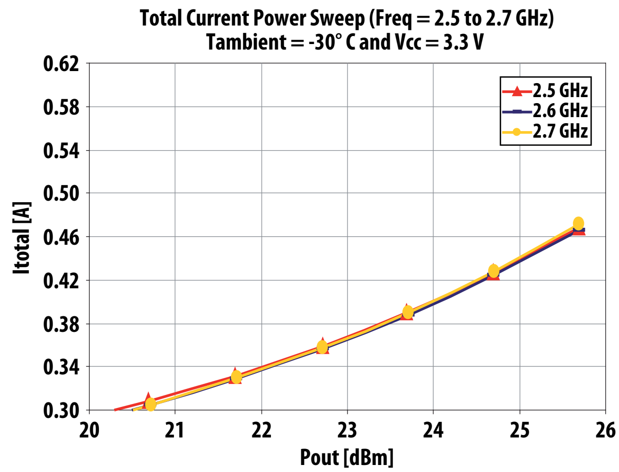


Figure 15. Total Current Power Sweep at 3.3 V and -30° C over Frequency

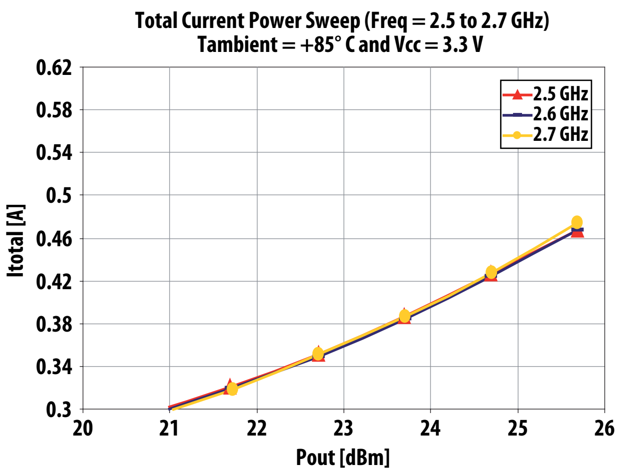


Figure 16. Total Current Power Sweep at 3.3 V and +85° C over Frequency

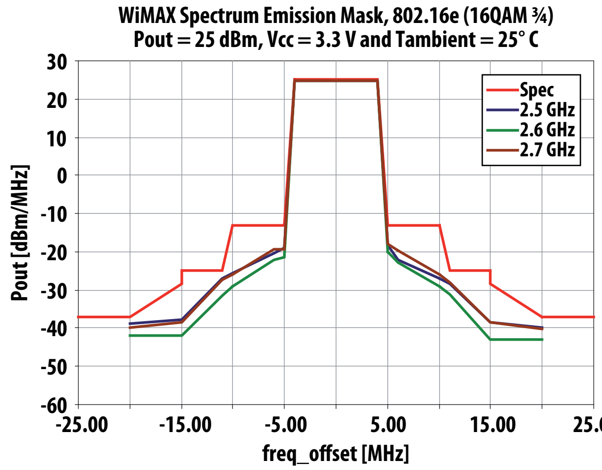


Figure 17. SEM Frequency Sweep at Vcc = 3.3 V and 25° C (2 dB Post-PA loss assumed)

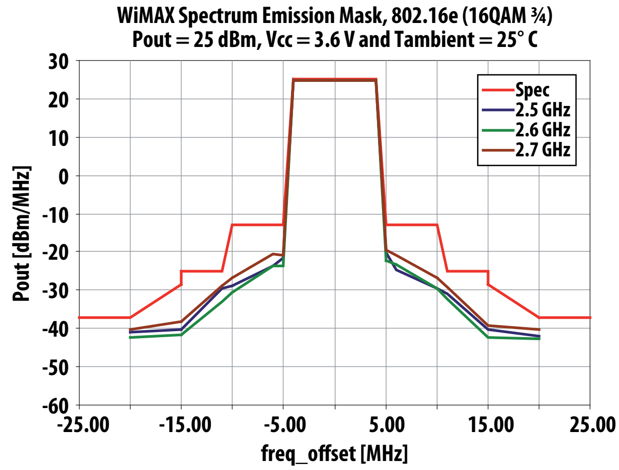


Figure 18. SEM Frequency Sweep at Vcc = 3.6 V and 25° C (2dB Post-PA loss assumed)

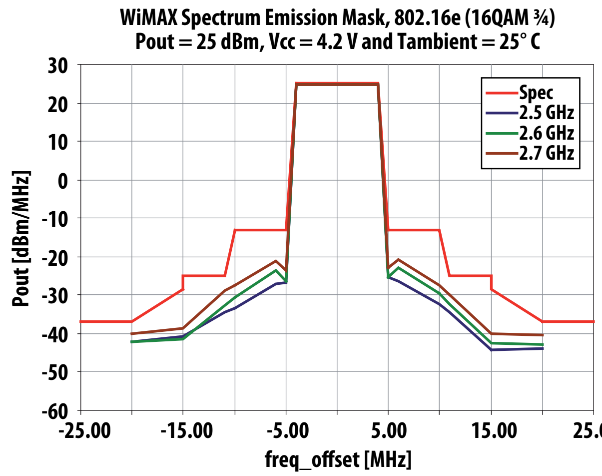


Figure 19. SEM Frequency Sweep at Vcc = 4.2 V and 25° C (2 dB Post-PA loss assumed)

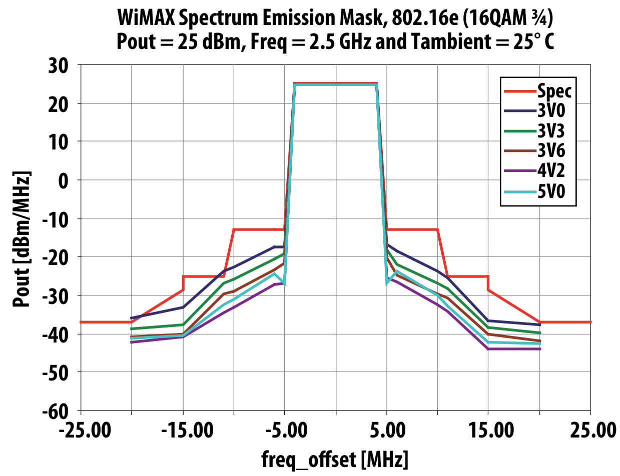


Figure 20. SEM at Vcc = 3.3 V, 25° C and 2.5 GHz over Vcc (2dB Post-PA loss assumed)

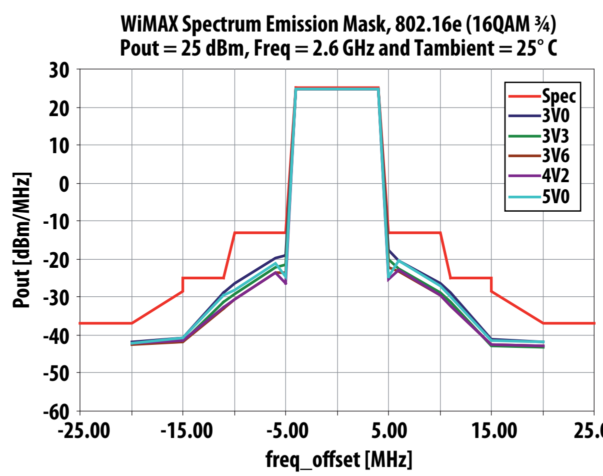


Figure 21. SEM at Vcc = 3.3 V, 25° C and 2.6 GHz over Vcc (2 dB Post-PA loss assumed)

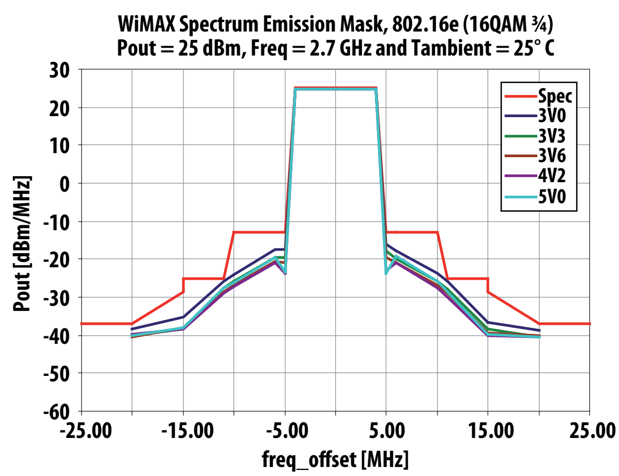


Figure 22. SEM at Vcc = 3.3 V, 25° C and 2.7 GHz over Vcc (2dB Post-PA loss assumed)

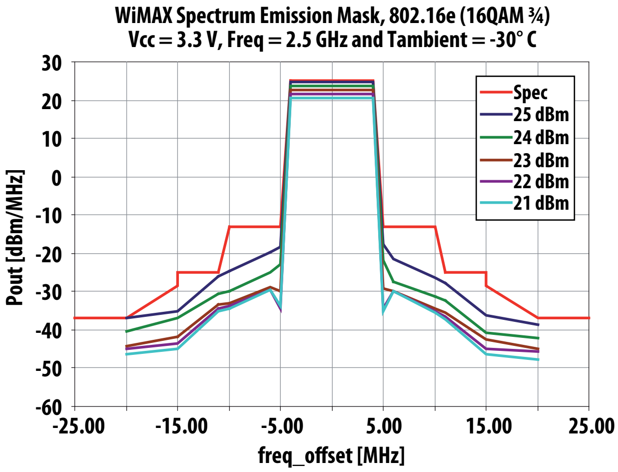


Figure 23. SEM at Vcc = 3.3 V, -30° C and 2.5 GHz over Vcc (2 dB Post-PA loss assumed)

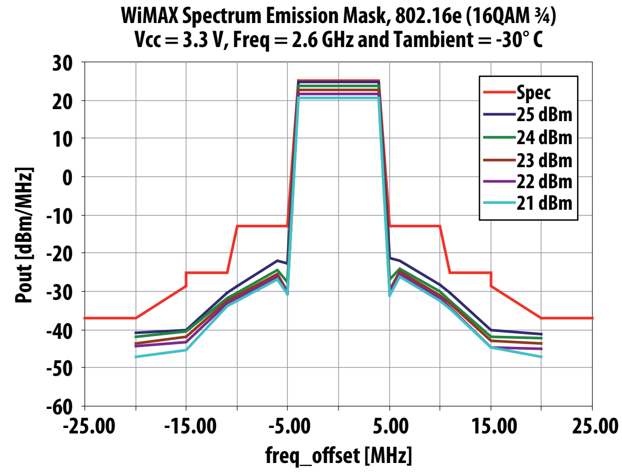


Figure 24. SEM at Vcc = 3.3 V, -30° C and 2.6 GHz over Vcc (2 dB Post-PA loss assumed)

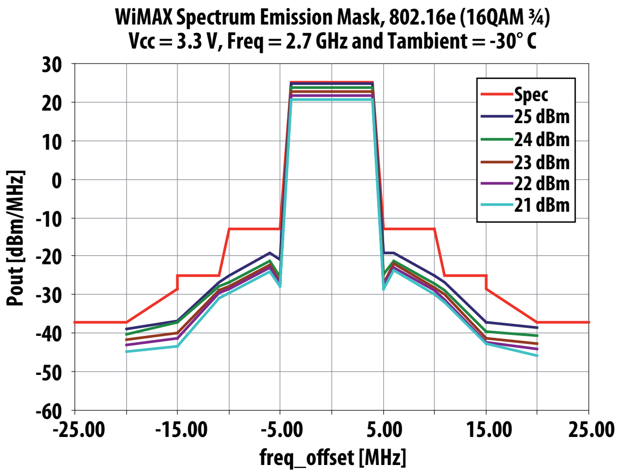


Figure 25. SEM at Vcc = 3.3 V, -30° C and 2.7 GHz over Vcc (2 dB Post-PA loss assumed)

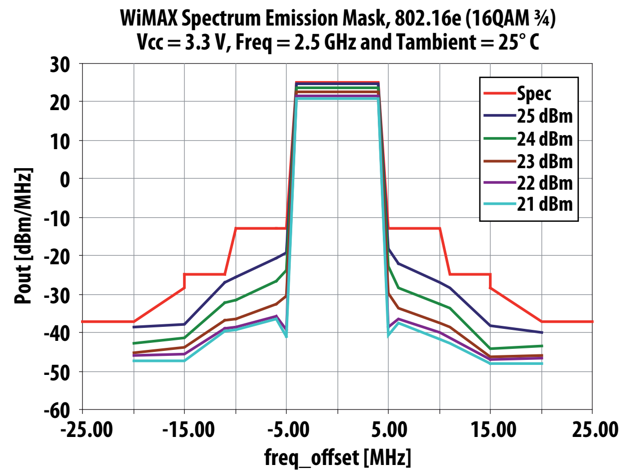


Figure 26. SEM at Vcc = 3.3 V, 25° C and 2.5 GHz over Vcc (2 dB Post-PA loss assumed)

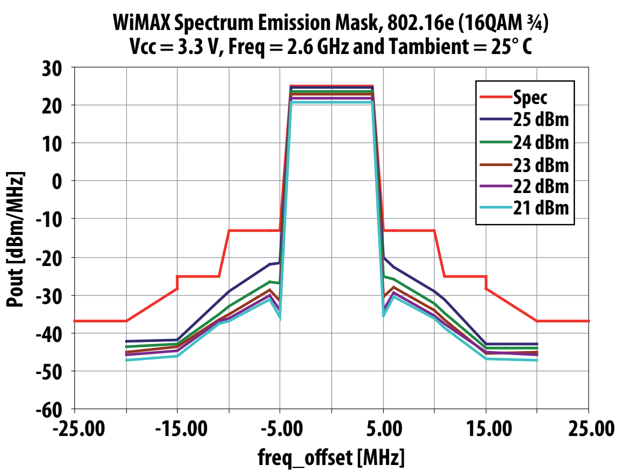


Figure 27. SEM at Vcc = 3.3 V, 25° C and 2.6 GHz over Vcc (2 dB Post-PA loss assumed)

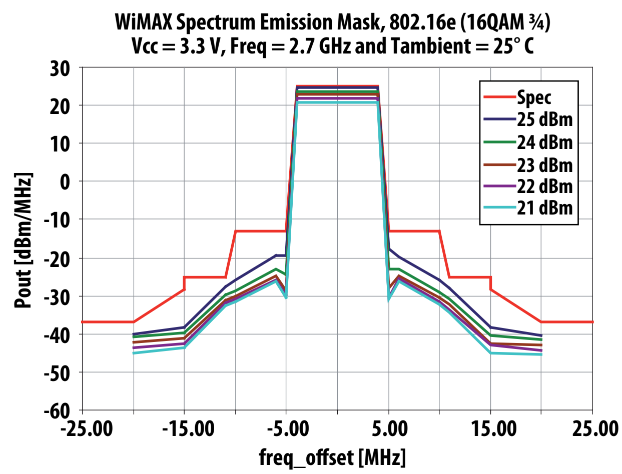


Figure 28. SEM at Vcc = 3.3 V, 25° C and 2.7 GHz over Vcc (2 dB Post-PA loss assumed)

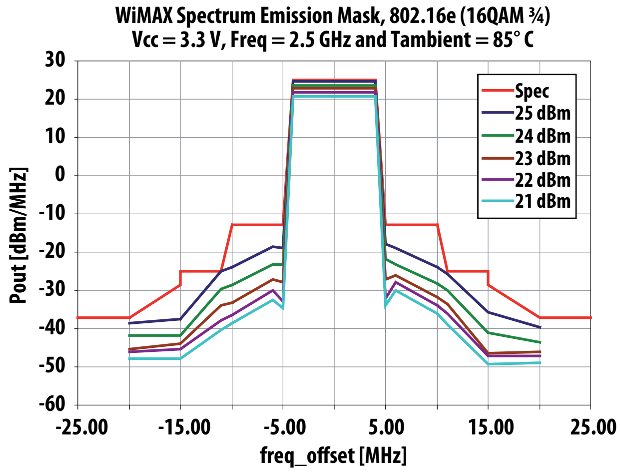


Figure 29. SEM at Vcc = 3.3 V, +85° C and 2.5 GHz over Vcc (2 dB Post-PA loss assumed)

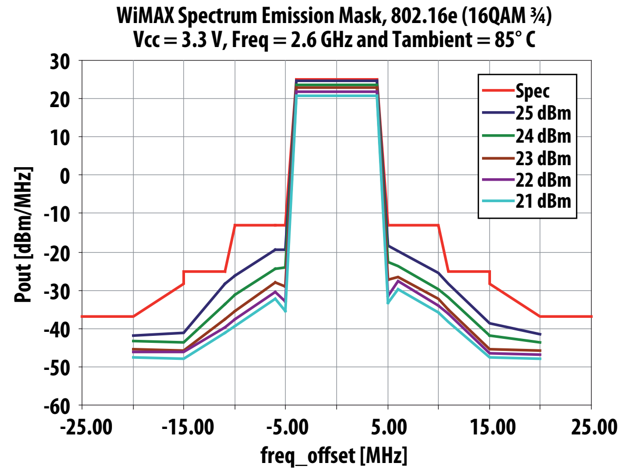


Figure 30. SEM at Vcc = 3.3 V, +85° C and 2.6 GHz over Vcc (2 dB Post-PA loss assumed)

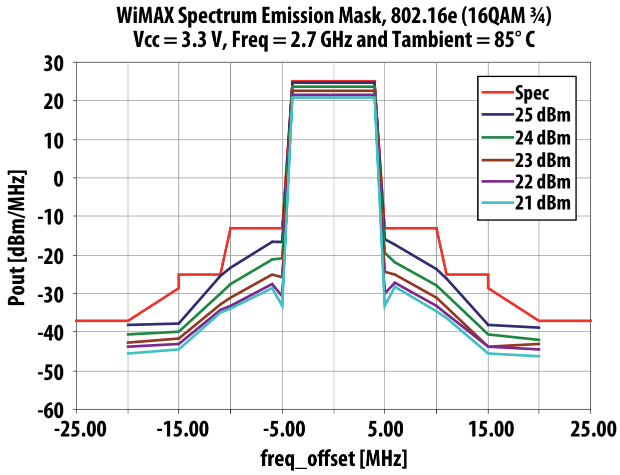


Figure 31. SEM at Vcc = 3.3 V, +85° C and 2.7 GHz over Vcc (2 dB Post-PA loss assumed)

Evaluation Board Description

Table 4. Pin Description:

Top Pin No.	Function
1	VCC2
3	B_SPLY
5	VCC1
7	NC
9	PAMOD
11	NC
13	NC
15	B_CTRL
17	NC
19	NC

Bottom Pin No.	Function
2	VCC2
4	GND
6	GND
8	GND
10	GND
12	GND
14	B_SW
16	GND
18	GND
20	GND

Recommended turn on sequence

- Apply VCC1 and VCC2
- Apply BSPLY
- Apply BCTRL
- Apply BSW
- For HPM Apply PAMOD HI
- For LPM Apply PAMOD LO
- Apply RF Input not to exceed 15 dBm

Turn off in reverse order

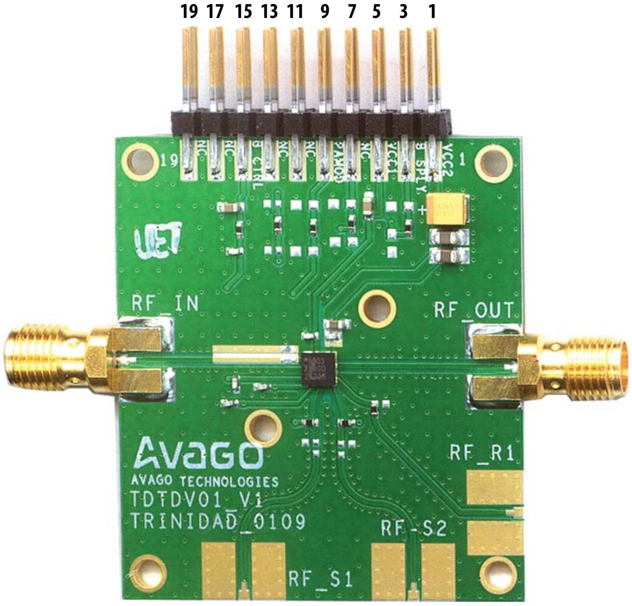
Table 5. Typical Test Conditions:

Pin	HPM	LPM	
VCC1, 2	3.3 V	3.3 V	Supply Voltage
PAMOD	1.8 V	0 V	Low Power Mode
B_SPLY	3.3 V	3.3 V	Bias Voltage
B_CTRL	2.8 V	2.8 V	Bias Control
B_SW	1.8 V	1.8 V	PA Enable

Notes: VCC1, VCC2 and B_SPLY can be tied together to reduce supply voltages, but B_CTRL needs to be a regulated voltage which is optimized for 2.8 V at Vcc of 3.3 V. Other bias points are described under flexible BCTRL optimization section.

Demoboard Top Pins

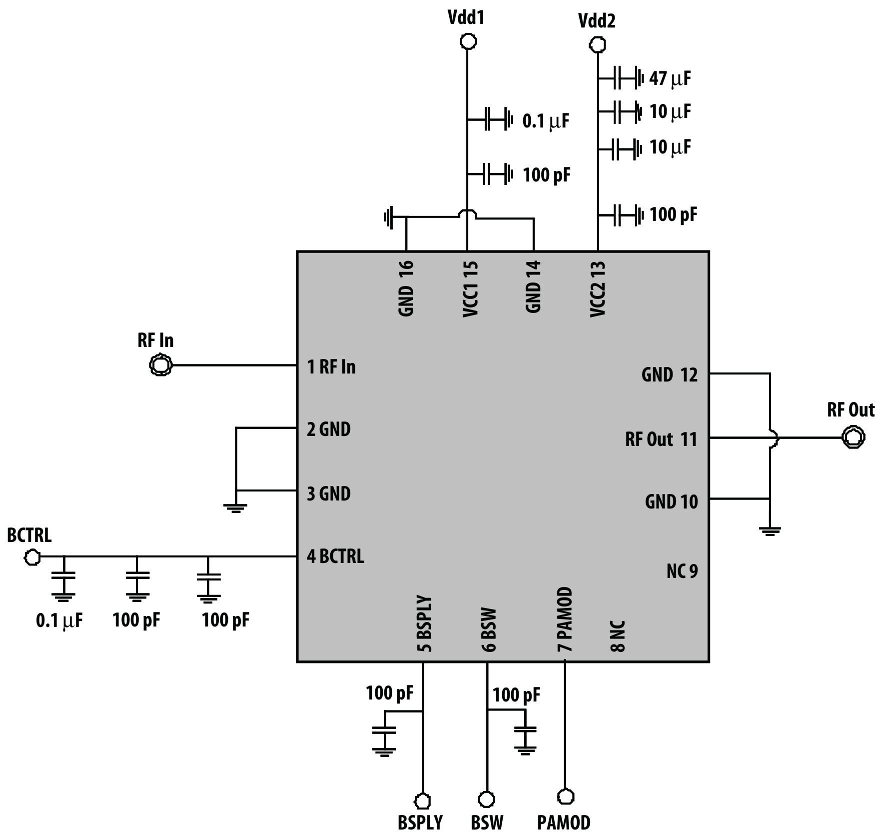
19 17 15 13 11 9 7 5 3 1



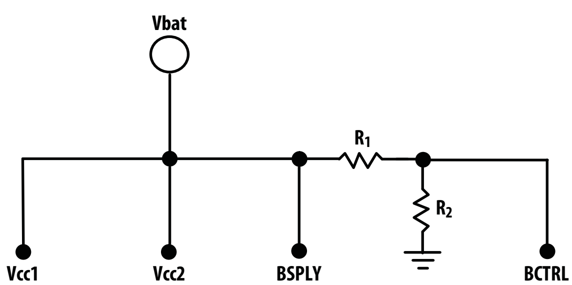
Demoboard Bottom Pins

2 4 6 8 10 12 14 16 18 20

Application Circuit MGA-22103



Using 3.3 V or 5 V Supply and connecting Vcc1, Vcc2, BSLPY and BCTRL



Notes:

BCTRL regulates the device current, thus R1 and R2 should have good tolerance rating. If available, a voltage regulator is the preferred method of bias.

In this example we set R2 at 10 MOhm and solve for R1 with simple voltage divider equation. Use high resistance values to limit leakage current.

3.3 V Example:

$$V_{BCTRL} = \frac{R_2}{R_1 + R_2} * V_{BATT}$$

$$2.85\ V = \frac{10\ M\Omega}{R_1 + 10\ M\Omega} * 3.3\ V$$

$R_1 = 1.\ 58\ M\Omega$

$R_2 = 10\ M\Omega$

Given:

$V_{BCTRL} = 2.85\ V$

$V_{BAT} = 3.3\ V$

$R_2 = 10\ M$

$R_1 = ?$

5.0 V Example:

$$V_{BCTRL} = \frac{R_2}{R_1 + R_2} * V_{BATT}$$

$$2.85\ V = \frac{10\ M\Omega}{R_1 + 10\ M\Omega} * 5.0\ V$$

$R_1 = 7.54\ M\Omega$

$R_2 = 10\ M\Omega$

Given:

$V_{BCTRL} = 2.85\ V$

$V_{BAT} = 5.0\ V$

$R_2 = 10\ M$

$R_1 = ?$

Land Pattern

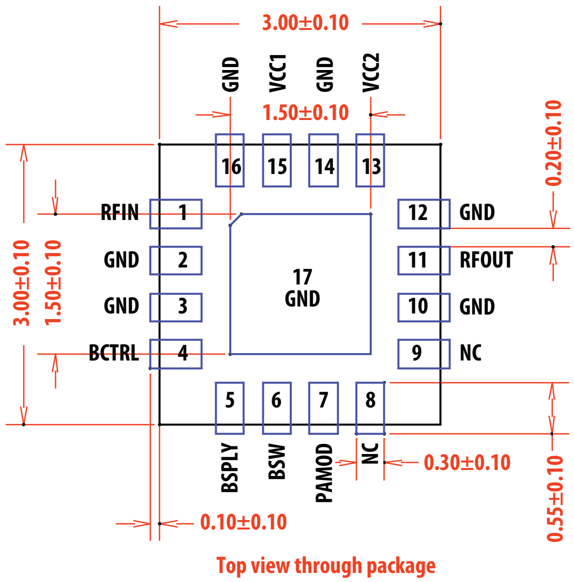


Figure 32. Recommended footprint

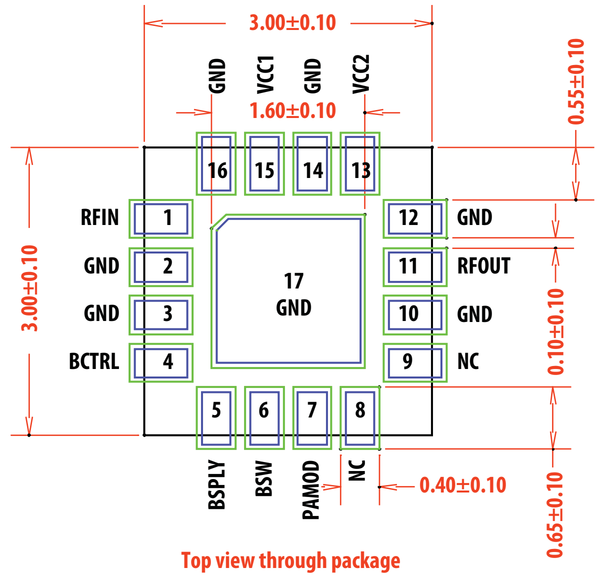


Figure 33. Recommended soldermask opening

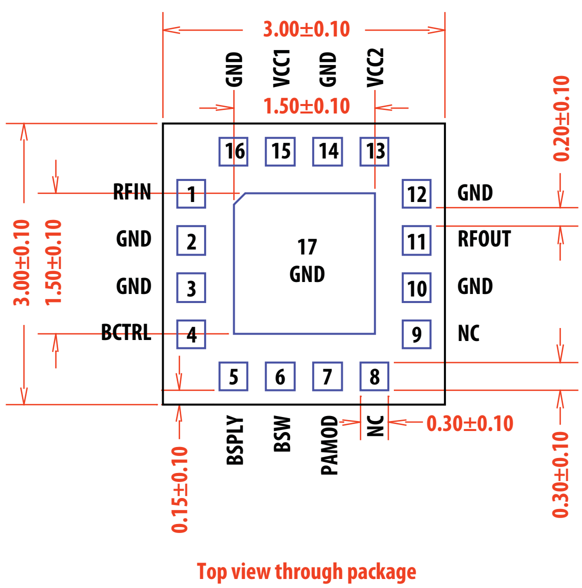
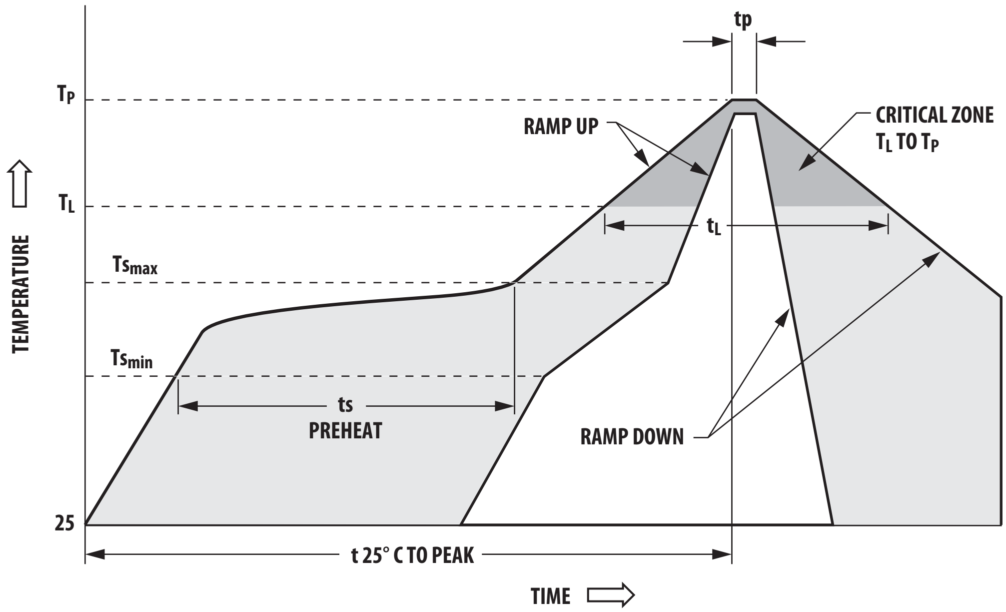


Figure 34. Package dimensions

Notes:
1. All units are in millimeters
2. Package is symmetrical

Handling and Storage

Typical SMT Reflow Profile for Maximum Temperature = 260+0/-5° C

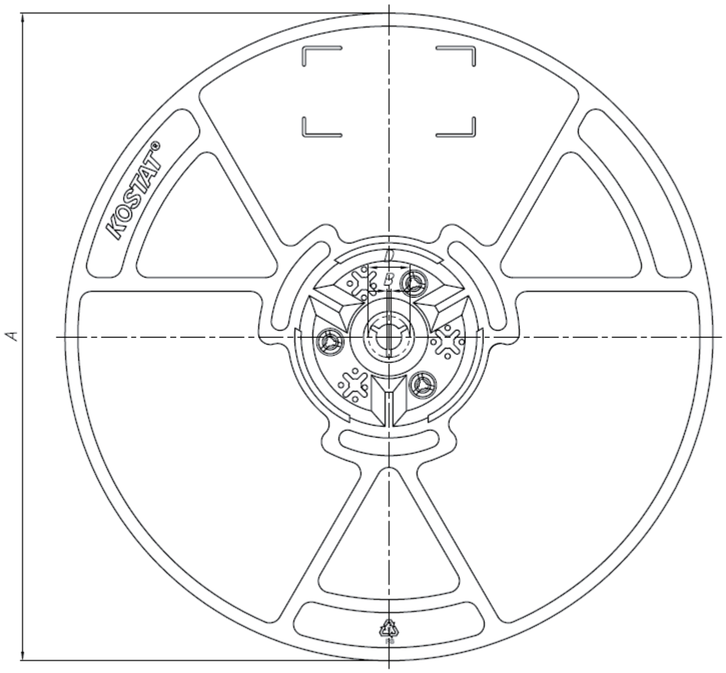


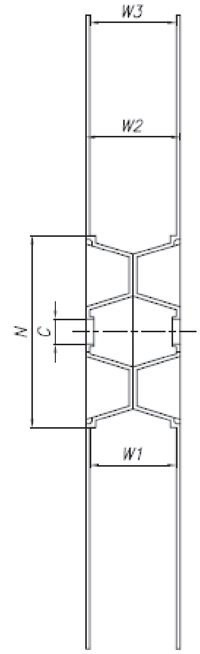
Profile Feature	Sn-Pb Solder	Pb-Free Solder
Average ramp-up rate (TL to TP)	3°C/sec max	3°C/sec max
Preheat – Temperature Min (Tsmin) – Temperature Max (Tsmax) – Time (mon to max) (ts)	 100° C 150° C 60-120 sec	 100° C 150° C 60-180 sec
Tsmax to TL – Ramp-up Rate		 3°C/sec max
Time maintained above: – Temperature (TL) – Time (TL)	 183° C 60-150 sec	 217° C 60-150 sec
Peak temperature (Tp)	240 +0/-5° C	260 +0/-5° C
Time within 5° C of actual Peak Temperature (tp)	10-30 sec	10-30 sec
Ramp-down Rate	6°C/sec max	6°C/sec max
Time 25° C to Peak Temperature	6 min max	8 min max

MGA-22103 Part Number Ordering Information

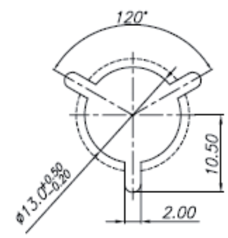
Part Number	Devices Per Container	Container
MGA-22103-BLKG	10	Antistatic bag
MGA-22103-TR1G	3000	13" Reel

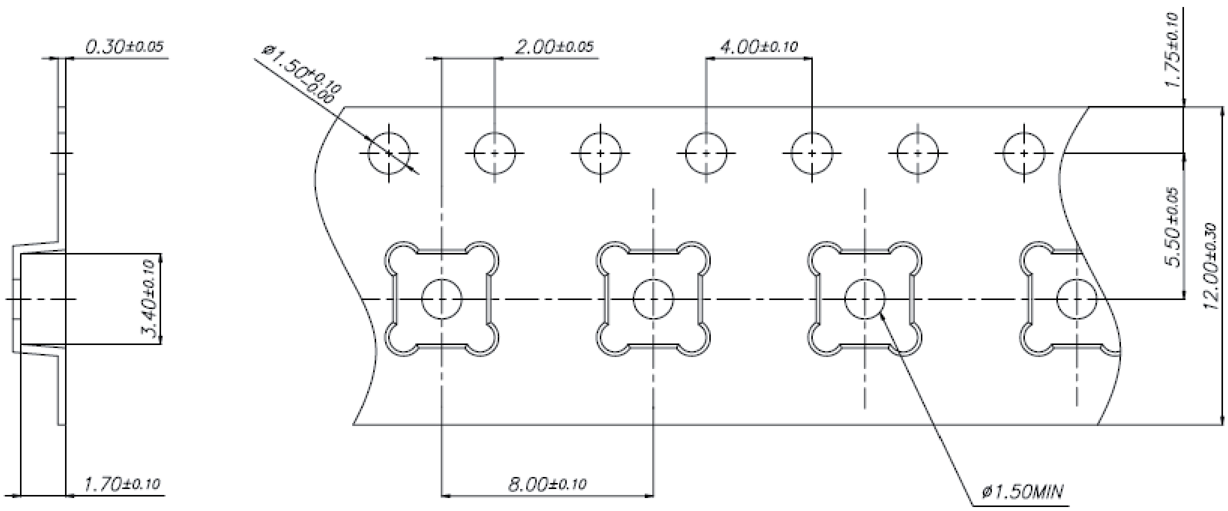
Tape and Reel Information

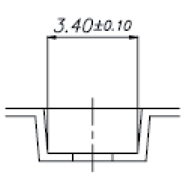




Size	12mm
A	$330^{+2.0}_{-2.0}$
B	1.5min.
C	$13.0^{+0.5}_{-0.2}$
D	20.2min.
N	$100^{+3.0}_{-0.0}$
W1	$12.4^{+3.0}_{-0.0}$
W2	$16.4^{+2.0}_{-2.0}$
W3	$13.65^{+1.75}_{-0.75}$







For product information and a complete list of distributors, please go to our web site: **www.avagotech.com**

AV02-2812EN - February 17, 2011